

**Vishay Semiconductors** 

# High Speed Infrared Emitting Diode, RoHS Compliant, 830 nm, GaAlAs Double Hetero



## DESCRIPTION

VSMG2700 is an infrared, 830 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a PLCC-2 package for surface mounting (SMD).

## **FEATURES**

- Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- Peak wavelength:  $\lambda_p = 830 \text{ nm}$
- · High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity:  $\varphi = \pm 60^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- High modulation band width: fc = 18 MHz
- · Good spectral matching with Si photodetectors
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

## **APPLICATIONS**

- Infrared radiation source for operation with CMOS cameras (illumination)
- High speed IR data transmission

# PRODUCT SUMMARY

COMPONENT	l <sub>e</sub> (mW/sr)	φ <b>(deg)</b>	λ <sub>P</sub> (nm)	t <sub>r</sub> (ns)	
VSMG2700	10	± 60	830	20	

#### Note

Test conditions see table "Basic Characteristics"

## **ORDERING INFORMATION**

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMG2700-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2		
VSMG2700-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2		

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	A	
Power dissipation		Pv	180	mW	



# Vishay Semiconductors

# High Speed Infrared Emitting Diode, RoHS Compliant, 830 nm, GaAlAs Double Hetero



ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	acc. figure 8, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R <sub>thJA</sub>	250	K/W

Note

 $T_{amb}$  = 25 °C, unless otherwise specified

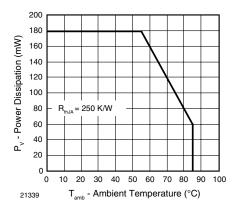


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

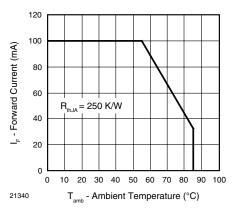


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERIST PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	V <sub>F</sub>		1.5	1.8	V
Forward voltage	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>		2.3		V
Temperature coefficient of $V_F$	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.8		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	Cj		125		pF
De die et interesity	l <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	l <sub>e</sub>	6	10	22	mW/sr
Radiant intensity	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>		100	1.8	mW/sr
Radiant power	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	φ <sub>e</sub>		40		mW
Temperature coefficient of $\phi_{e}$	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 60		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λ <sub>p</sub>		830		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		40		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA	tr		20		ns
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		20		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f <sub>c</sub>		18		MHz
Virtual source diameter		d		0.44	1	mm

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified



High Speed Infrared Emitting Diode, RoHS Compliant, 830 nm, GaAIAs Double Hetero

**Vishay Semiconductors** 

**VSMG2700** 

# **BASIC CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

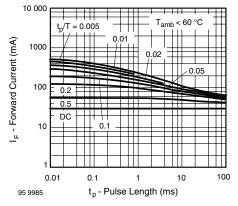


Fig. 3 - Pulse Forward Current vs. Pulse Duration

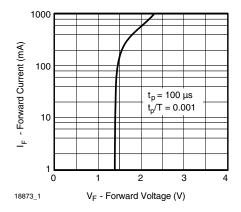


Fig. 4 - Forward Current vs. Forward Voltage

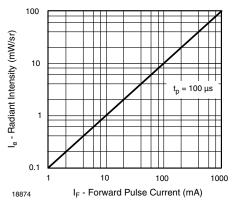


Fig. 5 - Radiant Intensity vs. Forward Current

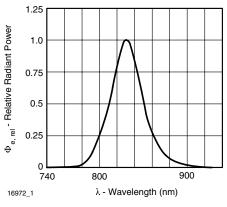


Fig. 6 - Relative Radiant Power vs. Wavelength

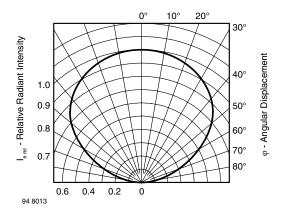


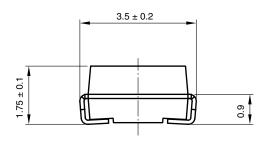
Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

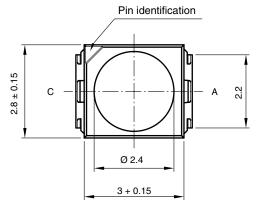
# **Vishay Semiconductors**

High Speed Infrared Emitting Diode, RoHS Compliant, 830 nm, GaAlAs Double Hetero



# **PACKAGE DIMENSIONS** in millimeters

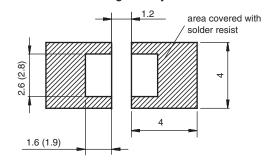




Mounting Pad Layout

technical drawings according to DIN

specifications



Drawing-No.: 6.541-5067.01-4 Issue: 4; 30.07.07 20541

## SOLDER PROFILE

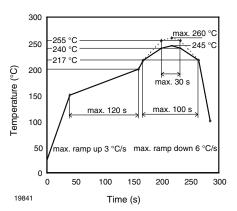


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

## DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

## **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks Conditions:  $T_{amb} < 30$  °C, RH < 60 % Moisture sensitivity level 2a, acc. to J-STD-020.

## DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

#### **TAPE AND REEL**

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.



Adhesive tape

Component cavity

2.05 1.95

Fig. 9 - Blister Tape

# **VSMG2700**

# High Speed Infrared Emitting Diode, RoHS Compliant, 830 nm, GaAlAs Double Hetero

Blister tape

94 8670

0.25

94 8668

# Vishay Semiconductors

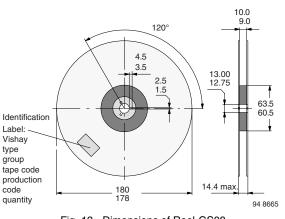


Fig. 12 - Dimensions of Reel-GS08

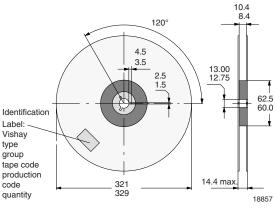


Fig. 13 - Dimensions of Reel-GS18

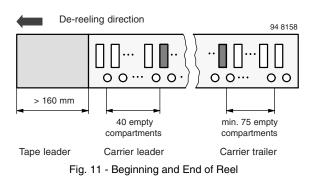
## **COVER TAPE REMOVAL FORCE**

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of  $180^{\circ}$  with regard to the feed direction.

# **MISSING DEVICES**

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.

Fig. 10 - Tape Dimensions in mm for PLCC-2



The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.



Vishay

# Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.